

COMPLIMENTARY PAIR ENHANCEMENT MODE MOSFETS

This space-efficient device contains an electrically-isolated complimentary pair of enhancement-mode MOSFETs (one N-channel and one P-channel). It comes in a very small SOT-363 package. This device is ideal for portable applications where board space is at a premium.

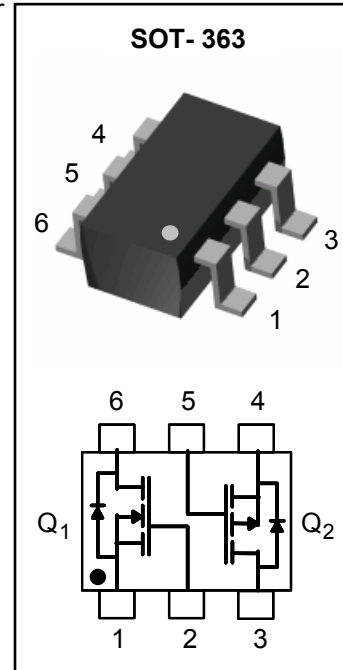
FEATURES

- Complimentary Pairs
- Low On-Resistance
- Low Gate Threshold Voltage
- Fast Switching
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. . (Halogen Free)

APPLICATIONS

- Switching Power Supplies
- Hand-Held Computers, PDAs

MARKING CODE: S82



MAXIMUM RATINGS - TOTAL DEVICE $T_J = 25^\circ\text{C}$ Unless otherwise noted

Rating	Symbol	Value	Units
Total Power Dissipation (Note 1)	P_D	200	mW
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

MAXIMUM RATINGS N - CHANNEL - Q_1 , 2N7002 $T_J = 25^\circ\text{C}$ Unless otherwise noted

Rating	Symbol	Value	Units
Drain-Source Voltage	V_{DSS}	60	V
Drain-Gate Voltage $R_{GS} < 1.0\text{Mohm}$	V_{DGR}	60	V
Gate-Source Voltage - Continuous	V_{GSS}	± 20	V
Drain Current - Continuous (Note 1)	I_D	115	mA

MAXIMUM RATINGS P - CHANNEL - Q_2 , BSS84 $T_J = 25^\circ\text{C}$ Unless otherwise noted

Rating	Symbol	Value	Units
Drain-Source Voltage	V_{DSS}	-50	V
Drain-Gate Voltage $R_{GS} < 20\text{Kohm}$	V_{DGR}	-50	V
Gate-Source Voltage - Continuous	V_{GSS}	± 20	V
Drain Current - Continuous (Note 1)	I_D	130	mA

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Units
Thermal Resistance, Junction to Ambient (Note 1)	R_{thja}	625	$^\circ\text{C/W}$

Note 1. FR-5 board 1.0 x 0.75 x 0.062 inch with minimum recommended pad layout

Electrical Characteristics - N-CHANNEL - Q₁ , 2N7002 $T_J = 25^\circ\text{C}$ Unless otherwise noted

OFF CHARACTERISTICS (Note 2)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D = 10\mu\text{A}, V_{GS} = 0\text{V}$	60	80	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 60\text{V}, V_{GS} = 0$ $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	-	-	1.0 500	μA
Gate-Body Leakage	I_{GSS}	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$	-	-	± 10	nA

ON CHARACTERISTICS (Note 2)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	1.0	1.6	2.5	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = 5\text{V}, I_D = 0.05\text{A}$ $V_{GS} = 10\text{V}, I_D = 0.5\text{A}$	-	1.8 2.0	4.5 7.0	Ohms
On-State Drain Current	$I_{D(ON)}$	$V_{GS} = 10\text{V}, V_{DS} = 7.5\text{V}$	0.5	1.65	-	A
Forward Transconductance	g_{FS}	$V_{DS} = 10\text{V}, I_D = 0.2\text{A}$	0.08	-	-	S

DYNAMIC CHARACTERISTICS

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Input Capacitance	C_{iss}	$V_{DS} = 25\text{V},$ $V_{GS} = 0\text{V},$ $f = 1.0\text{MHz}$	-	-	50	pF
Output Capacitance	C_{oss}		-	-	25	pF
Reverse Transfer Capacitance	C_{rss}		-	-	5.0	pF

SWITCHING CHARACTERISTICS

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Turn-On Delay Time	$t_{D(ON)}$	$V_{DD} = 30\text{V}, I_D = 0.2\text{A}, R_L = 150\text{ohm}$ $R_{GEN} = 25\text{ohm}, V_{GEN} = 10\text{V}$	-	-	20	ns
Turn-Off Delay Time	$t_{D(OFF)}$		-	-	20	ns

Note 2. Short duration test pulse used to minimize self-heating

Electrical Characteristics - P-CHANNEL - Q₂ , BSS84 $T_J = 25^\circ\text{C}$ Unless otherwise noted

OFF CHARACTERISTICS (Note 3)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D = -250\mu\text{A}, V_{GS} = 0\text{V}$	-50	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -50\text{V}, V_{GS} = 0\text{V}, T_J = 25^\circ\text{C}$	-	-	-15	μA
		$V_{DS} = -50\text{V}, V_{GS} = 0\text{V}, T_J = 125^\circ\text{C}$	-	-	-60	
		$V_{DS} = -25\text{V}, V_{GS} = 0\text{V}, T_J = 25^\circ\text{C}$	-	-	-0.1	
Gate-Body Leakage	I_{GSS}	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$	-	-	± 10	nA

ON CHARACTERISTICS (Note 3)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -1\text{mA}$	-0.8	1.44	-2.0	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = -5\text{V}, I_D = -0.1\text{A}$	-	3.8	10	Ohms
Forward Transconductance	g_{FS}	$V_{DS} = -25\text{V}, I_D = -0.1\text{A}$	0.05	-	-	S

DYNAMIC CHARACTERISTICS

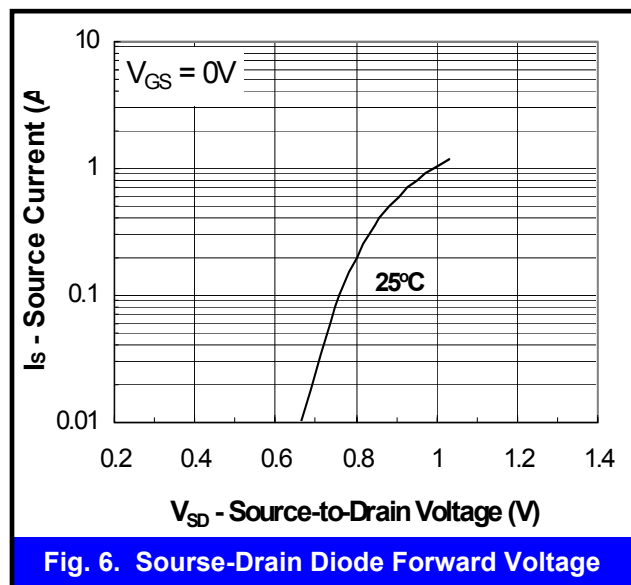
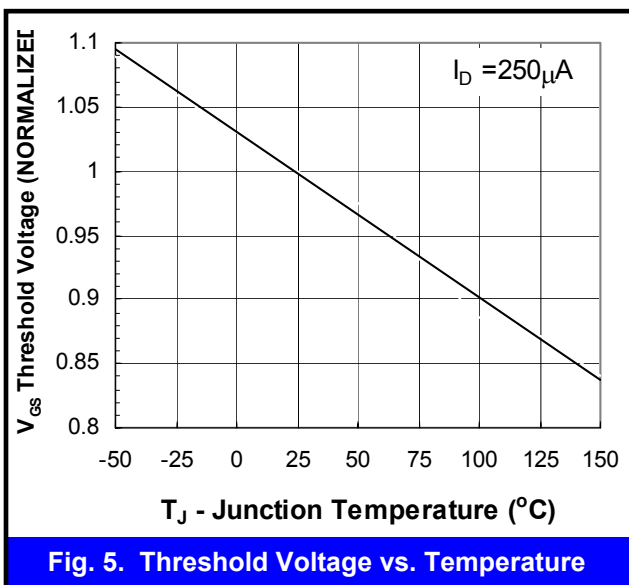
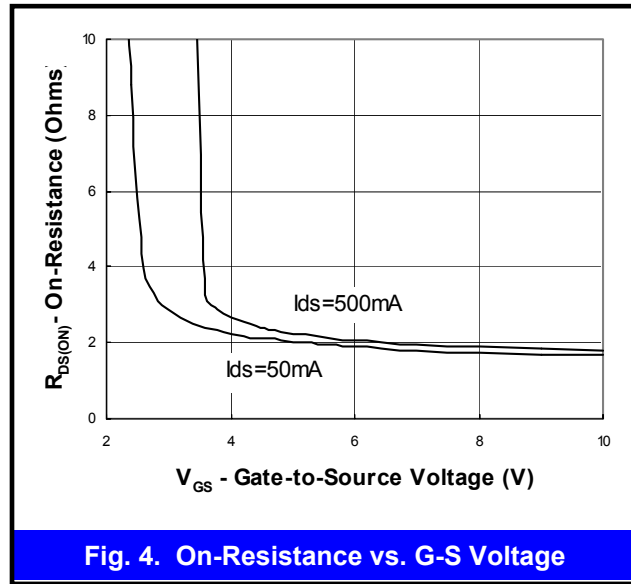
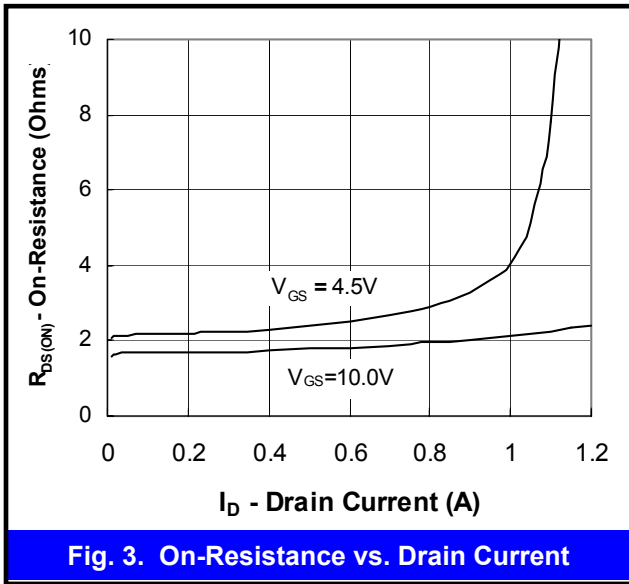
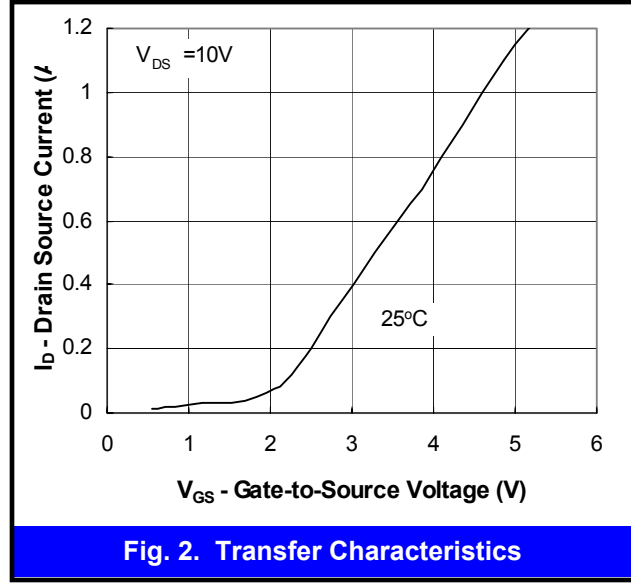
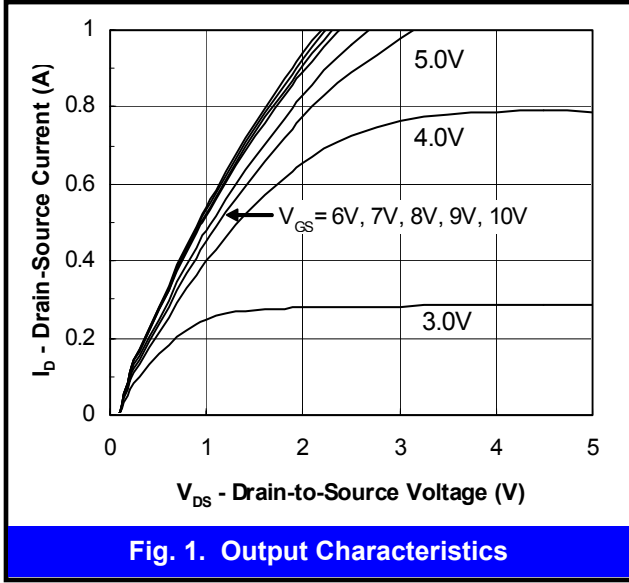
Parameter	Symbol	Conditions	Min	Typ	Max	Units
Input Capacitance	C_{iss}	$V_{DS} = -25\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$	-	-	45	pF
Output Capacitance	C_{oss}		-	-	25	pF
Reverse Transfer Capacitance	C_{rss}		-	-	12	pF

SWITCHING CHARACTERISTICS

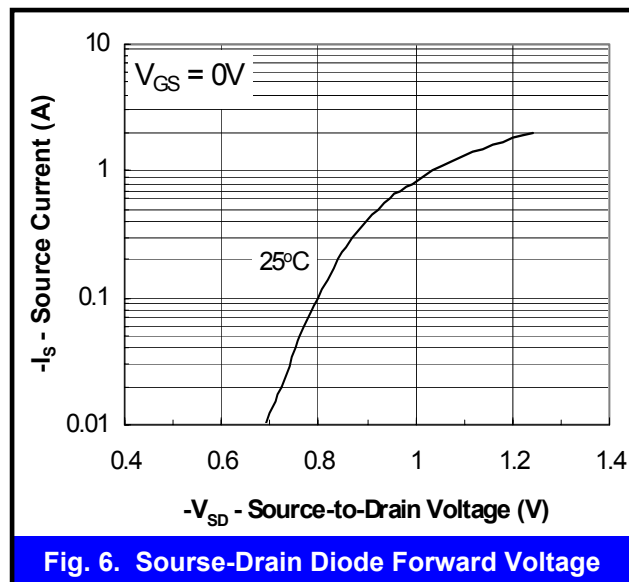
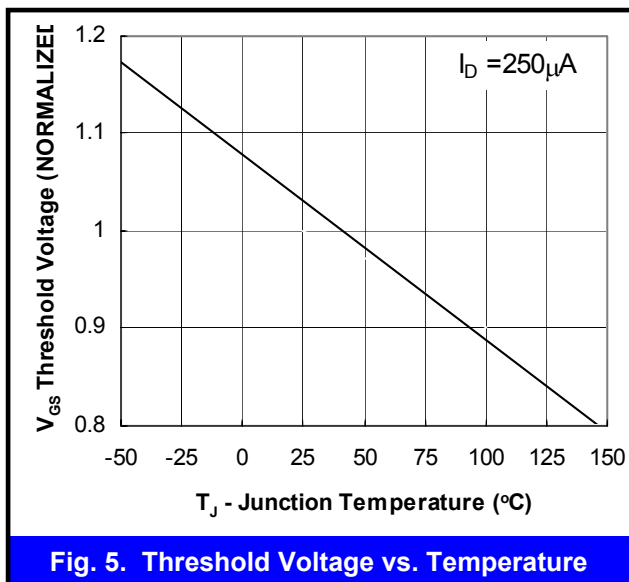
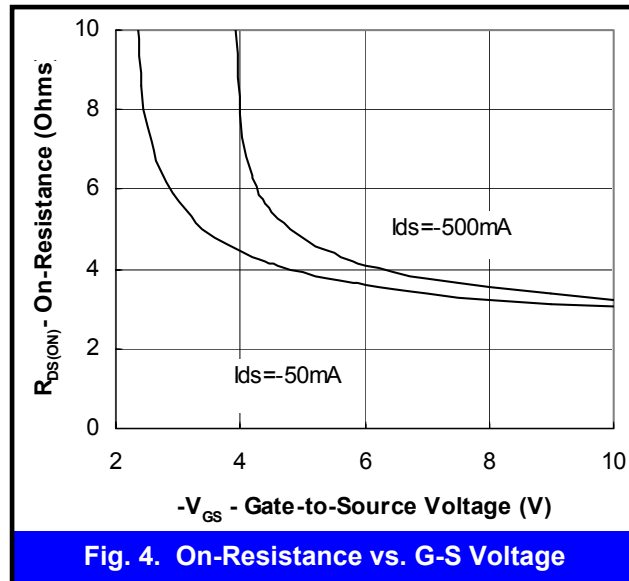
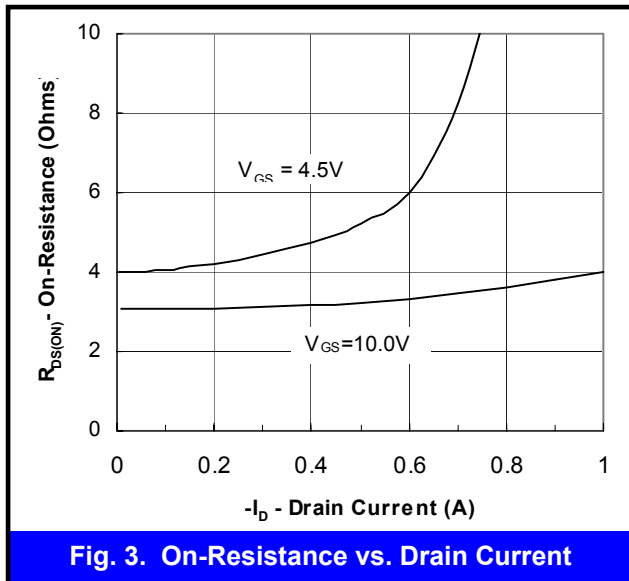
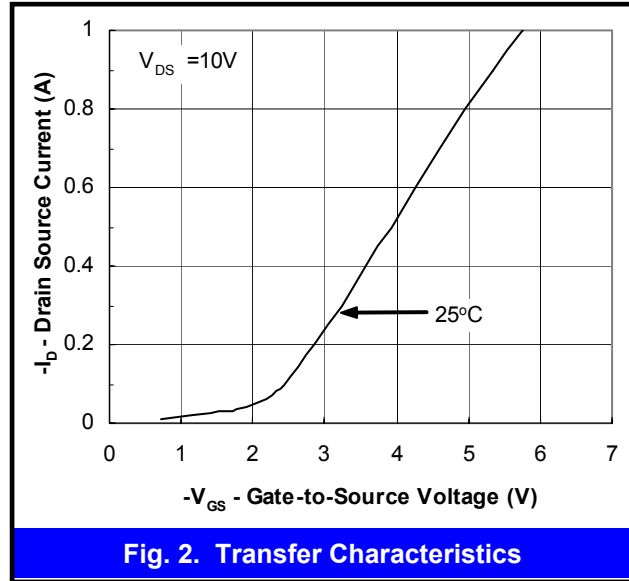
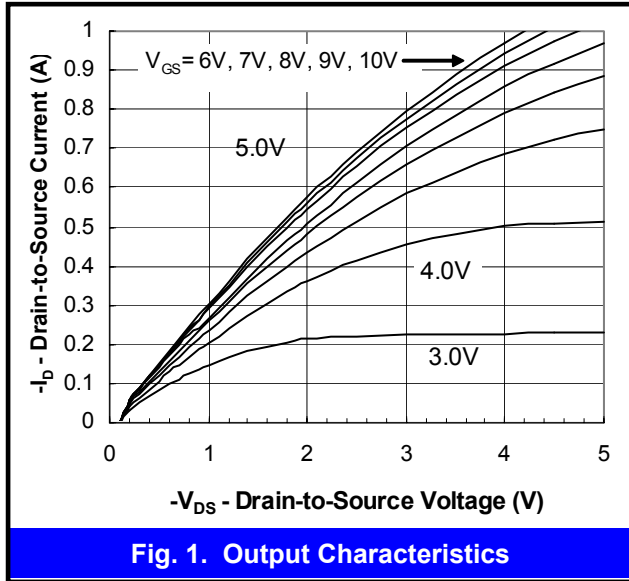
Parameter	Symbol	Conditions	Min	Typ	Max	Units
Turn-On Delay Time	$t_{D(ON)}$	$V_{DD} = -30\text{V}, I_D = -0.27\text{A}, R_{GEN} = 50\text{ohm}, V_{GS} = -10\text{V}$	-	7.5	-	ns
Turn-Off Delay Time	$t_{D(OFF)}$		-	25	-	ns

Note 3. Short duration test pulse used to minimize self-heating

Typical Characteristics Curves - N-Channel - Q₁, 2N7002 $T_J = 25^\circ\text{C}$ Unless otherwise noted

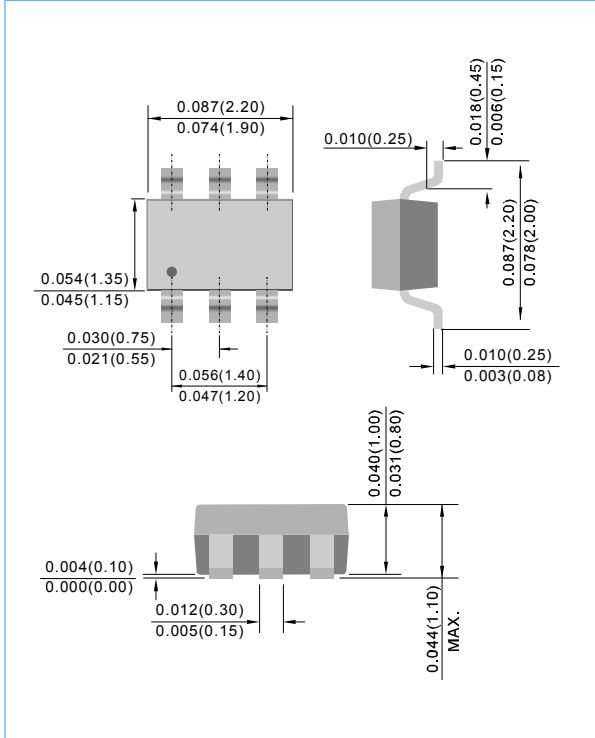


Electrical Characteristic Curves - P-Channel - Q₂, BSS84 T_J = 25°C Unless otherwise noted

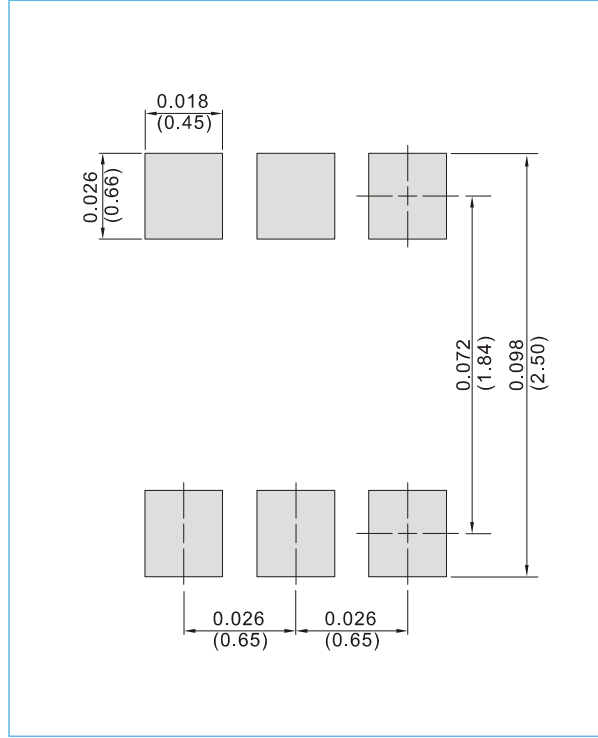


PACKAGE LAYOUT AND SUGGESTED PAD DIMENSIONS

SOT-363 Unit : inch(mm)



SOT-363 Unit : inch(mm)



ORDERING INFORMATION

BSS8402DW T/R7: 7 inch reel, 3K units per reel, Pin 1 towards tape sprocket holes

BSS8402DW T/R7-R: 7 inch reel, 3K units per reel, Pin 1 away from tape sprocket holes

BSS8402DW T/R13: 13 inch reel, 10K units per reel, Pin 1 towards tape sprocket holes

BSS8402DW T/R13-R: 13 inch reel, 10K units per reel, Pin 1 away from tape sprocket holes



BSS8402DW

Part No_packing code_Version

BSS8402DW_R1_00001

BSS8402DW_R2_00001

For example :

RB500V-40_R2_00001



Packing Code XX				Version Code XXXXX		
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			



BSS8402DW

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